NSN 5962-01-370-1470

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, schottky, bipolar 65536 bit prom
Voltage Rating And Type Per Characteristic:
-0.3 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
55.00 nanoseconds af output megawatts
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:

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